

# 2STC2510

## High power NPN epitaxial planar bipolar transistor

### Features

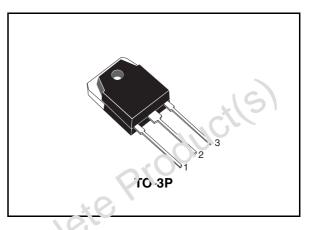
- High breakdown voltage V<sub>CEO</sub> = 100 V
- Complementary to 2STA2510
- Typical f<sub>t</sub> = 20 MHz
- Fully characterized at 125 °C

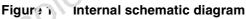
### Application

Audio power amplifier

### Description

The device is a NPN transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.





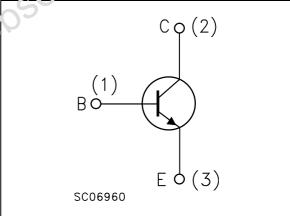


Table 1. Device summary

Order code	Marking	Package	Packaging
2STC2510	2STC2510	TO-3P	Tube

#### **Electrical ratings** 1

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	100	V
V <sub>CEO</sub>	Collector-emitter voltage ( $I_B = 0$ )	100	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	6	V
۱ <sub>C</sub>	Collector current	25	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	50	А
P <sub>TOT</sub>	Total dissipation at $T_c = 25 \text{ °C}$	125	W
T <sub>stg</sub>	Storage temperature	-65 ic 15'J	°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C

#### Table 3. Thermal data

0				
Table 3.	Thermal data	×0 <sup>×</sup>		
Symbo	DI Parameter	Value	Unit	
R <sub>thj-case</sub> Thermal resistance junction-case		۲ ( ۲	°C/W	
	.15)			
	oroduct(S)			
	PIOU			
olete				
0/0				



## 2 Electrical characteristics

(T<sub>case</sub> = 25 °C; unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current $(I_E = 0)$	V <sub>CB</sub> = 100 V			10	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 6 V			10	μA
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage ( $I_B = 0$ )	I <sub>C</sub> = 50 mA	100		J'S	v
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	l <sub>C</sub> = 100 μA	100	00		V
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 1 mA	6			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = 12 A I <sub>B</sub> = 1.2 A			1.5	V
$V_{BE}^{(1)}$	Base-emitter voltage	$V_{CE} = 4$ / $I_{C} = 12$ A			1.8	V
h <sub>FE</sub>	DC current gain	$I_{C} = 12 \text{ A}$ $V_{CE} = 4 \text{ V}$	40		80	
f <sub>T</sub>	Transition frequer cy	I <sub>C</sub> = 0.5 A V <sub>CE</sub> = 12 V		20		MHz

#### Table 4. Electrical characteristics

1. Pulsed duration = 300 μs, duty cycle ≤ 1.5 %

57

### 2.1 Electrical characteristic (curves)

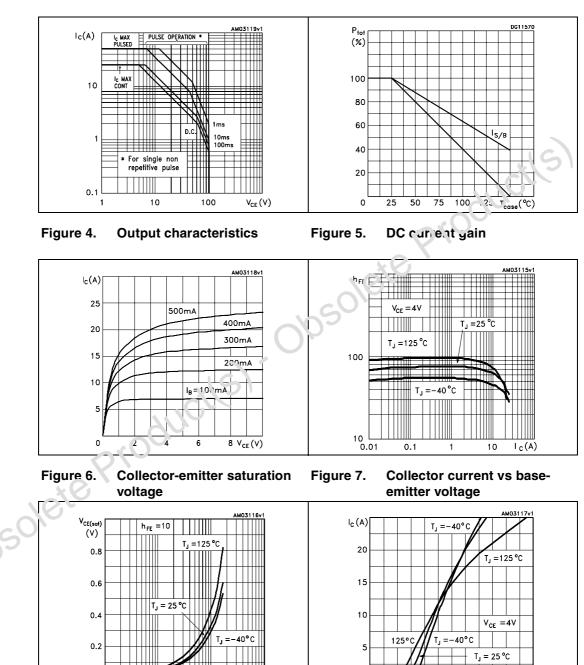


Figure 3.

**Derating curve** 

#### Figure 2. Safe operating area

## 57

0

1

10

I<sub>c</sub>(A)

0

0.5

1

1.5 2

 $V_{BE}(V)$ 

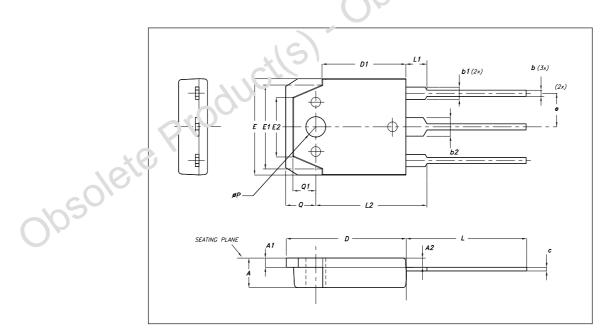
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

obsolete Product(s). Obsolete Product(s)



	mm.		DIM.
MAX.	ТҮР	MIN.	
5		4.6	A
1.65	1.50	1.45	A1
1.60	1.40	1.20	A2
1.20	1	0.80	b
2.20		1.80	b1
3.20		2.80	b2
0.75	0.60	0.55	С
20.10	19.90	19.70	D
 11	13.90		D1
15.80		15.40	E
	13.60		E1
	9.60		E2
 5.75	5.45	5.15	е
20.50	20	19.50	L
	3.50		L1
18.60	18.40	18.20	L2
 3.30		3.10	P
	5		Q
	3.81		Q1





## 4 Revision history

Table 5. Document revision history

	Date	Revision	Changes
	27-Nov-2007	1	Initial release
	16-May-2008	2	Document status promoted from preliminary data to datasheet.
	14-Nov-2008	3	Added paragraph: Electrical characteristic (curves) on page 4
obsol	etepro	duct	Added paragraph: Electrical characteristic (curves) on page 4



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